

a flash memory device coupled to communicate with the processor via a serial bus and communicate with the synchronous memory device via a direct bus, wherein the flash memory device transfers data directly to the synchronous memory device during power-up.

7. The processing system of claim 6 wherein the synchronous memory device initiates the data transfer in response to a reset signal provided by an external reset controller.
8. The processing system of claim 7 wherein the synchronous memory device provides a system reset signal to the processor after the data is transferred from the flash memory device.
9. The processing system of claim 6 wherein the synchronous memory device is an SDRAM.
10. The processing system of claim 6 wherein the synchronous memory device is an RDRAM.
11. A processor system power-up method comprising:
 - detecting a power-up condition and providing a reset signal to a synchronous memory;
 - initiating a direct data transfer from a non-volatile memory to the synchronous memory in response to the reset signal; and
 - providing a system reset signal from the synchronous memory to a processor.
12. The method of claim 11 wherein the synchronous memory device is an SDRAM.

13. The method of claim 11 wherein the synchronous memory device is an RDRAM.
14. The method of claim 11 wherein the non-volatile memory is flash memory.
15. The method of claim 11 further comprises loading the non-volatile memory with the processor prior to detecting the power-up condition.
16. A method of improving a processor system power-up comprising:
detecting a power-up condition with a reset controller and providing a reset signal to a synchronous memory;
using the synchronous memory, initiating a direct data transfer from a flash memory to the synchronous memory in response to the reset signal; and
providing a system reset signal from the synchronous memory to a processor after the data has been transferred.
17. The method of claim 16 wherein the synchronous memory is coupled to the processor via a synchronous bus.
18. The method of claim 11 wherein the synchronous memory device is either an SDRAM or an RDRAM.
19. A method of increasing a processor system power-up speed comprising:
detecting a power-up condition with a reset controller and providing a reset signal to a synchronous dynamic random access memory (SDRAM);
using the SDRAM, initiating a direct data transfer from a flash memory to the synchronous memory in response to the reset signal; and
providing a system reset signal from the SDRAM to a processor after the data has been transferred.

20. A processor system power-up method comprising:
 - detecting a power-up condition with a reset controller and providing a reset signal to a rambus dynamic random access memory (RDRAM);
 - using the RDRAM, initiating a direct data transfer from a flash memory to the synchronous memory in response to the reset signal; and
 - providing a system reset signal from the RDRAM to a processor after the data has been transferred.
21. A data transfer method comprising:
 - initiating a direct data transfer from a non-volatile memory to a volatile storage device; and
 - transferring data from the non-volatile memory to the volatile storage device without control from an external processor.